

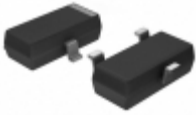


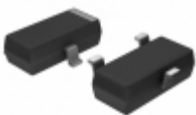
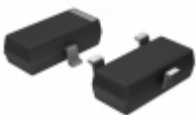


	<p>SI2302ADS-T1-E3</p>
	<p>Hersteller-Teilenummer: SI2302ADS-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 20V 2.1A SOT23-3</p> <p>Datenblätter:  SI2302ADS-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 447941 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI2302ADS-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 20V 2.1A SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	447941 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	700mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.1A (Ta)
Rds On (Max) @ Id, Vgs	60 mOhm @ 3.6A, 4.5V
VGS (th) (Max) @ Id	1.2V @ 50µA
Gate Charge (Qg) (Max) @ Vgs	10nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	300pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	2.5V, 4.5V
Vgs (Max)	±8V
Verpackung	Tape & Reel (TR)











SI2302ADS-T1-E3 ist neu im Original, Suche SI2302ADS-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2302ADS-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI2302ADS-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 SI2302ADS-T1-E3 VISHAY VISHAY SOT23	 SI2302ADS-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 2.1A SOT23-3	 SI2302ADS-T1-E1 VISHAY VISHAY SOT23	 SI2302ADS Original SI2302ADS Original
 SI2302ADS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 2.1A SOT23-3	 SI2302ADS-T1 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 2.1A SOT23-3	 SI2302ADS-T1-T3 Vishay Precision Group SI2302ADS-T1-T3 VISHAY	 SI2302ADS-T1-E3(2A). VIS VIS SOT-23

heiße Teile

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|  SI2301A1SHB |  SI2301ADS |  SI2301ADS-T1-E3 |  SI2301ADS-T1-GE3 |  SI2301BDS |
|  SI2301BDS-E3 |  SI2301BDS-T1 |  SI2301BDS-T1-E3 |  SI2301BDS-T1-GE3 |  SI2301BDS-T1-GE3 |
|  SI2301BDS-T1-GE3 |  SI2301CDS |  SI2301CDS-T1-E3 |  SI2301CDS-T1-GE3 |  SI2301CDS-T1-GE3 |
|  SI2301CDS-T1-GE3 |  SI2301DS |  SI2301DS-E3 |  SI2301DS-T1 |  SI2301DS-T1-E3 |
|  SI2301DS-T1-GE3 |  SI2302ADS |  SI2302ADS-T1 |  SI2302ADS-T1 |  SI2302ADS-T1-E3 |
|  SI2302ADS-T1-GE3 |  SI2302ADS-T1-GE3 |  SI2302BDS-T1-E3 |  SI2302CDS-T1-E3 |  SI2302CDS-T1-E3 |
|  SI2302CDS-T1-GE3 |  SI2302CDS-T1-GE3 |  SI2302DDS-T1-GE3 |  SI2302DDS-T1-GE3 |  SI2302DS |
|  SI2302DS-E3 |  SI2302DS-T1 |  SI2302DS-T1-E3 |  SI2302DS-T1-GE3 |  SI2302DV |
|  SI2302WCB |  SI2303ADS-T1-GE3 |  SI2303BDS |  SI2303BDS-T |  SI2303BDS-T1 |
|  SI2303BDS-T1 |  SI2303BDS-T1-E3 |  SI2303BDS-T1-E3 |  SI2303BDS-T1-GE3 |  SI2303BDS-T1-GE3 |

Contact us: Info@Y-IC.com

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